TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC4512BP, TC4512BF, TC4512BFN

TC4512B 8 - CHANNEL DATA SELECTOR

TC4512B is data selector which selects 8 channel data inputs (X0 through×7) according to binary address inputs A, B and C. Since high impedance can be given to output Z by setting DISABLE input to "H", the wired-OR arrangement can be achieved. DISABLE input takes precedence over other inputs giving the output high impedance.

If DISABLE="L" and INHIBIT="H", the data select operation is inhibited and output Z becomes "L" Level.

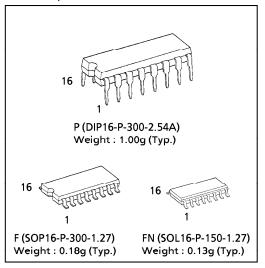
MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNIT
DC Supply Voltage	V_{DD}	$V_{SS} - 0.5 \sim V_{SS} + 20$	V
Input Voltage	V _{IN}	$V_{SS} - 0.5 \sim V_{DD} + 0.5$	٧
Output Voltage	V _{OUT}	$V_{SS} - 0.5 \sim V_{DD} + 0.5$	V
DC Input Current	I _{IN}	± 10	mA
Power Dissipation	P _D	300 (DIP) / 180 (SOIC)	mW
Operating Temperature Range	T _{opr}	- 40∼8 5	°C
Storage Temperature Range	T _{stg}	− 65 ~150	°

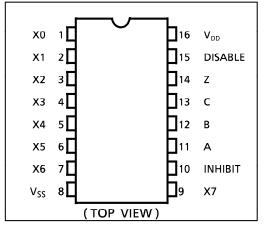
TRUTH TABLE

	OUTPUT				
Α	В	С	INHIBIT	DISABLE	Z
L	L	L	L	L	X0
Н	L	L	L	L	X1
L	Н	L	L	L	X2
Н	Н	L	L	L	Х3
L	L	Н	L	L	X4
Н	L	Н	L	L	X5
L	Н	Н	L	L	X6
Н	Н	Н	L	L	X7
*	*	*	Н	L	L
*	*	*	*	Н	HZ

* : DON'T CARE HZ : HIGH IMPEDANCE (Note) The JEDEC SOP (FN) is not available in Japan.

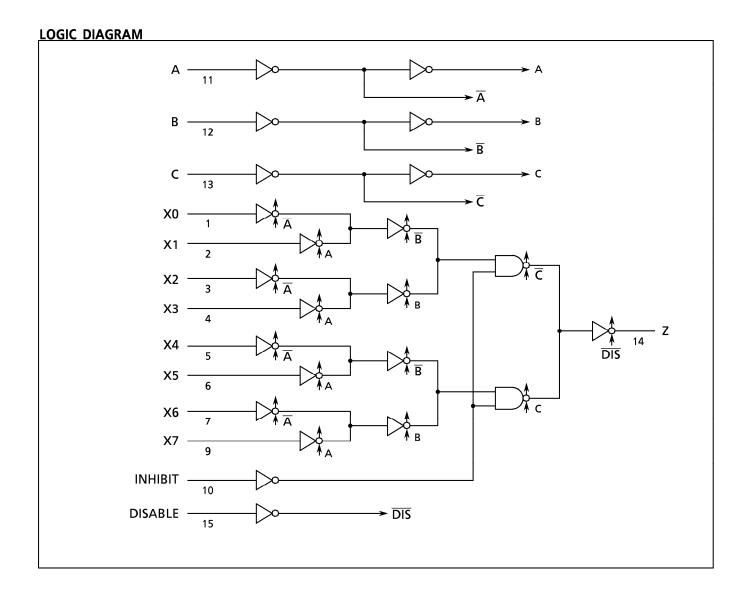


PIN ASSIGNMENT



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RECOMMENDED OPERATING CONDITIONS ($V_{SS} = 0V$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
DC Supply Voltage	V _{DD}		3	_	18	٧
Input Voltage	V _{IN}		0	_	V_{DD}	٧

STATIC ELECTRICAL CHARACTERISTICS ($V_{SS} = 0V$)

CHARACTERISTIC SYME		SYMBOL	TEST CONDITION	\ <u>/</u>	– 40°C		25°C			85°C		J _{UNIT}	
		STIVIBOL	L TEST CONDITION		MIN.	MAX.	MIN.	TYP.	MAX.	MIN.	MAX.		
High-Level Output Voltage		V _{OH}	$ I_{OUT} < 1\mu A$ $V_{IN} = V_{SS}, V_{DD}$	5 10 15	4.95 9.95 14.95	— —	4.95 9.95 14.95	5.00 10.00 15.00	_ _ _	4.95 9.95 14.95	_ _ _	,,	
Low-Level Output Voltage		V _{OL}	$\begin{aligned} I_{OUT} < 1\mu A \\ V_{IN} = V_{SS}, V_{DD} \end{aligned}$	5 10 15	_ _ _	0.05 0.05 0.05	_ _ _	0.00 0.00 0.00	0.05 0.05 0.05	_ _ _	0.05 0.05 0.05	V	
Output High Current		Іон	$V_{OH} = 4.6V$ $V_{OH} = 2.5V$ $V_{OH} = 9.5V$ $V_{OH} = 13.5V$ $V_{IN} = V_{SS}, V_{DD}$	5 10 15	- 0.61 - 2.5 - 1.5 - 4.0	_ _ _ _	- 0.51 - 2.1 - 1.3 - 3.4	- 1.0 - 4.0 - 2.2 - 9.0	_ _ _ _	- 0.42 - 1.7 - 1.1 - 2.8	_ _ _ _	mA	
Output Low Current		I _{OL}	$V_{OL} = 0.4V$ $V_{OL} = 0.5V$ $V_{OL} = 1.5V$ $V_{IN} = V_{SS}, V_{DD}$	5 10 15	0.61 1.5 4.0	_ _ _	0.51 1.3 3.4	1.2 3.2 12.0	_ _ _	0.42 1.1 2.8	_ _ _		
Input High Voltage \		V _{IH}	$V_{OUT} = 0.5V, 4.5V$ $V_{OUT} = 1.0V, 9.0V$ $V_{OUT} = 1.5V, 13.5V$ $ I_{OUT} < 1\mu A$	5 10 15	3.5 7.0 11.0		3.5 7.0 11.0	2.75 5.5 8.25		3.5 7.0 11.0			
Input Low Voltage		V _{IL}	$V_{OUT} = 0.5V, \ 4.5V$ $V_{OUT} = 1.0V, \ 9.0V$ $V_{OUT} = 1.5V, \ 13.5V$ $\left \ I_{OUT} \right < 1\mu A$	5 10 15		1.5 3.0 4.0	_ _ _	2.25 4.5 6.75	1.5 3.0 4.0		1.5 3.0 4.0	V	
Input Current	"H"Level	I _{IH}	V _{IH} = 18V	18	_	0.1	_	10-5	0.1	_	1.0	μΑ	
	"L" Level	I _{IL}	V _{IL} = 0V	18	_	- 0.1	_	- 10 ⁻⁵	-0.1	_	- 1.0	μ A	
3-State Output Leakage Current	"H"Level	I _{DH}	V _{OH} = 18V	18	_	0.4	_	10-4	0.4	_	12	μΑ	
	"L" Level	I _{DL}	V _{OL} = 0V	18	_	-0.4	_	- 10 ⁻⁴	-0.4	_	- 12		
Quiescent Current	Supply	I _{DD}	$V_{IN} = V_{SS}, V_{DD} *$	5 10 15		5 10 20	_ _ _	0.005 0.010 0.015	5 10 20	_	150 300 600	μΑ	

^{*} All valid input combinations.

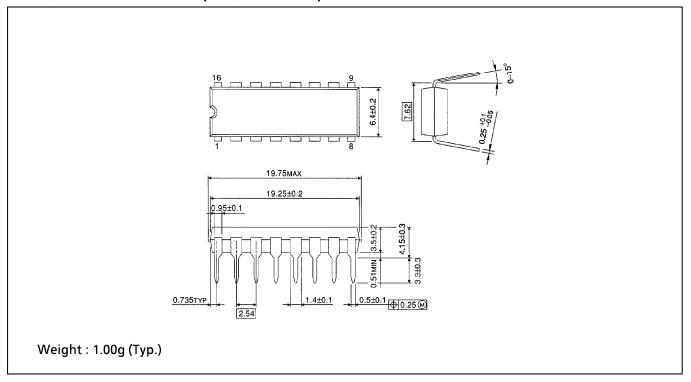
DYNAMIC ELECTRICAL CHARACTERISTICS (Ta = 25°C, Vss = 0V, $C_L = 50$ pF)

CHARACTERISTIC	SYMBOL	TEST CONDITION	V _{DD} (V)	MIN.	TYP.	MAX.	UNIT
Output Transition Time			5	_	80	200	
Output Transition Time	t _{TLH}		10	_	50	100	
(Low to High)			15	<u> </u>	40	80	
Output Transition Time			5		80	200	1
Output Transition Time	t _{THL}		10	_	50	100	
(High to Low)			15	_	40	80	
	_		5	_	140	280	
Propagation Delay Time (INHIBIT - Z)	t _{pLH}		10	_	60	140	
(INHIBIT - Z)	t _{pHL}		15	_	40	100	ns
Decreasing Dalay Time	_		5	_	240	400] '''
Propagation Delay Time (A, B, C - Z)	t _{pLH}		10	<u> </u>	95	170	
	t _{pHL}		15	<u> </u>	65	120	
Donas nation Dalay Time	_		5	_	210	360	
Propagation Delay Time	t _{pLH}		10	_	85	150	
(X - Z)	t _{pHL}		15	_	60	110	
Three State Disable Time (DISABLE - Z)			5	_	60	120	
	t_{pZL}, t_{pLZ}	$R_L = 1k\Omega$	10	_	25	60	
	t_{pHZ}, t_{pZH}		15	_	20	40	
Input Capacitance	C _{IN}		-	_	5	7.5	pF

WAVEFORM FOR MEASUREMENT OF DYNAMIC CHARACTERISTICS WAVEFORM 1 WAVEFORM 2(X = "H")20ns 20ns 20ns 20ns 90% 90% 90% 90% A, B, C **INHIBIT** 50% 50% 50% 50% 10% 10% 10% 10% $t_{\mathsf{TL} \overset{.}{\mathsf{H}}}$ t_{THL} 90% Ζ 90% 50% 50% 50% 50% 10% 10% t_{pLH} t_{pHL} $\mathsf{t}_{\mathsf{pHL}}$ t_{pLH} WAVEFORM 3 WAVEFORM 4 20ns 20ns 20ns 20ns 90% 90% 90% 90% Х **DISABLE** 50% 50% 50% 50% 10% 10% 10% 10% 90% Z Z 50% 50% 10% t_{pZL} t_{pLZ} 90% Z t_{pLH} $\mathsf{t}_{\mathsf{pHL}}$ 10% t_{pZH} $\mathsf{t}_{\mathsf{pHZ}}$

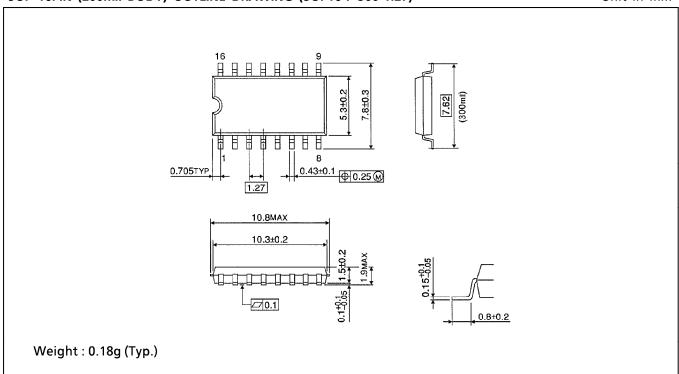
DIP 16PIN OUTLINE DRAWING (DIP16-P-300-2.54A)

Unit in mm



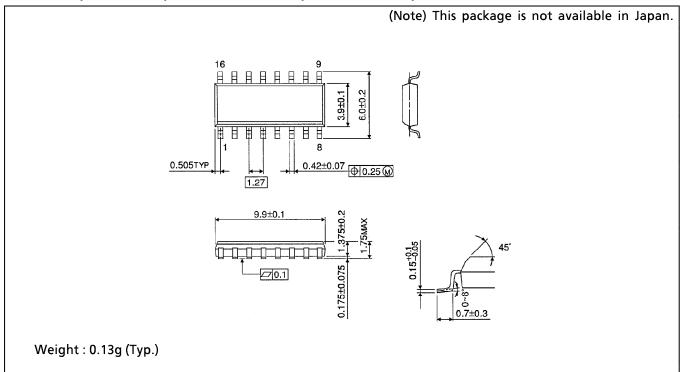
SOP 16PIN (200mil BODY) OUTLINE DRAWING (SOP16-P-300-1.27)

Unit in mm



SOP 16PIN (150mil BODY) OUTLINE DRAWING (SOL16-P-150 -1.27)

Unit in mm



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